NSN 5961-01-033-0818

Transistor - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5961-01-033-0818
Inclosure Material: Metal
Overall Length:
Between 0.065 inches and 0.085 inches
Terminal Length:
Between 0.500 inches and 0.750 inches
Overall Diameter:
Between 0.209 inches and 0.230 inches
Internal Configuration:
Junction contact
Mounting Method:
Terminal
Terminal Circle Diameter:
0.100 inches
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
-60.0 collector to base voltage/static/emitter open and -60.0 collector to emitter voltage/static/base open and -5.0 emitter to base voltage,
static, collector open
Current Rating Per Characteristic:
1.50 amperes source cutoff current
Power Rating Per Characteristic:
500.0 milliwatts small-signal input power, common-collector preset
Maximum Operating Tempurature Per Measurement Point:
200.0 degrees celsius ambient air
Special Features:
Junction pattern arrangement: pnp
Precious Material And Location:
Terminals gold
Precious Material:
Gold
Test Data Document:
81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).
Terminal Type And Quantity:
3 uninsulated wire lead
Specification Data:
81349-mil-s-19500/396 government specification

N/a

Shelf Life:

Unit Of Measure:

NSN 5961-01-033-0818

Transistor - Page 2 of 2



Demilitarization:

No

Fiig:

A110a0